

TECHNICAL DATA DATA SHEET 4770, REV.-

HERMETIC POWER SCHOTTKY RECTIFIER

(SINGLE / DUAL)

DESCRIPTION: A 150 VOLT, 45 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC LCC-3P PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ T_C = 25 °C UNLESS OTHERWISE SPECIFIED.

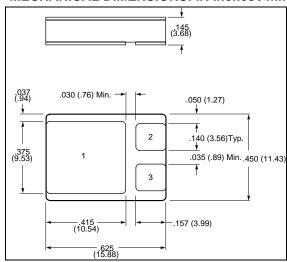
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RATING	SYMBOL	MAX.	UNITS	
PEAK INVERSE VOLTAGE	PIV	150	Volts	
MAXIMUM DC OUTPUT CURRENT With Cathode Maintained (@ T_c =100 $^{\circ}$ C) (Single)	Io	45	Amps	
MAXIMUM DC OUTPUT CURRENT With Cathode Maintained (@ T_c =100 $^{\circ}$ C) (Common Cathode)	Io	45	Amps	
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t = 8.3ms, Sine)	I _{FSM}	1650	Amps	
MAXIMUM JUNCTION CAPACITANCE (V _r =5V)	C _T	3000	pF	
MAXIMUM THERMAL RESISTANCE	R _{eJC}	0.25	°C/W	
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 175	°C	

ELECTRICAL CHARACTERISTICS

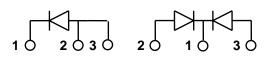
CHARACTERISTIC			
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (I _f = 45 Amps)			
T _J = 25 °C	V_{f}	0.96	Volts
T _J = 125 °C		0.77	
MAXIMUM REVERSE CURRENT (I _r @ 150 V PIV)			
T _J = 25 °C	l _r	3	mA
T _J = 125 °C		48	

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MECHANICAL DIMENSIONS: IN Inches / mm







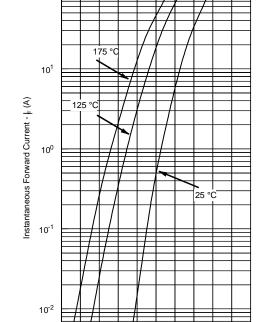
LCC-3P

PINOUT TABLE

10²

0.0

DEVICE TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
COMMON CATHODE	COMMON CATHODE	ANODE 1	ANODE 2

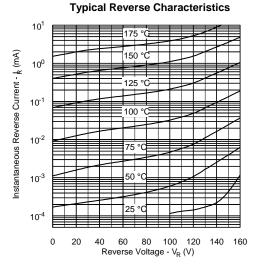


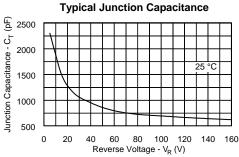
0.4

0.6

Forward Voltage Drop - V_F (V)

Typical Forward Characteristics







TECHNICAL DATA

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